SLVS011A - OCTOBER 1982 - REVISED NOVEMBER 1991

- 3-Terminal Regulators
- Output Current Up to 100 mA
- No External Components Required
- Internal Thermal Overload Protection
- Internal Short-Circuit Current Limiting
- Direct Replacement for Motorola MC79L00 Series
- Available in 5% or 10% Selections

description

This series of fixed negative-voltage monolithic integrated-circuit voltage regulators is designed for a wide range of applications. These include on-card regulation for elimination of noise and distribution problems associated with single-point regulation. In addition, they can be used to control series pass elements to make high-current voltage-regulator circuits. One of these regulators can deliver up to 100 mA of output current. The internal current-limiting and thermal-shutdownfeatures make them essentially immune to overload. When used as a replacement for a zener diode and resistor combination, these devices can provide an effective improvement in output impedance of two orders of magnitude and lower bias current.

equivalent schematic



NC-No internal connection

NOMINAL	5%	10%
OUTPUT	OUTPUT VOLTAGE	OUTPUT VOLTAGE
VOLTAGE	TOLERANCE	TOLERANCE
-5 V	MC79L05AC	MC79L05C
-12 V	MC79L12AC	MC79L12C
-15 V	MC79L15AC	



PRODUCTION DATA information is current as of publication date. Products conform to specifications per the terms of Texas Instruments standard warranty. Production processing does not necessarily include testing of all parameters.



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absolute maximum ratings over operating temperature ranges (unless otherwise noted)

	MC79L05	MC79LI2 MC79L15	UNIT		
Input voltage	-30	-35	V		
Continuous total dissipation	See Dissipation Rating Tables 1 and 2				
Operating free-air, case, or virtual junction temperature range	0 to 150	0 to 150	°C		
Storage temperature range	-65 to 150	-65 to 150	°C		
Lead temperature 1,6 mm (1/16 inch) from case for 10 seconds	260	260	°C		

DISSIPATION RATING TABLE 1 – FREE-AIR TEMPERATURE

PACKAGE	T _A ≤ 25°C POWER RATING	DERATING FACTOR	DERATE ABOVE T _A	T _A = 70°C POWER RATING
D	825 mW	6.6 mW/°C	25°C	528 mW
LP†	775 mW	6.2 mW/°C	25°C	496 mW
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[†] The LP package dissipation rating is based on thermal resistance measured in still air with the device mounted in an Augat socket. The bottom of the package was 10 mm (0.375 in.) above the socket.

DISSIPATION RATING TABLE 2 – CASE TEMPERATURE

PACKAGE	T _C ≤ 25°C POWER RATING	DERATING FACTOR	DERATE ABOVE T _C	T _C = 125°C POWER RATING
D	1600 mW	29.0 mW/°C	95°C	725 mW
LP	1600 mW	28.6 mW/°C	94°C	715 mW

recommended operating conditions

		MIN	MAX	UNIT
	MC79L05	-7 -20		
Input voltage, VI	MC79L12	-14.5	-27	V
	MC79L15	-17.5	-30	
Output current, IO		100	mA	
Operating virtual junction temperature, TJ		0	125	°C



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electrical characteristics at specified virtual junction temperature, $V_I = -10 V$, $I_O = 40 mA$ (unless otherwise noted)

BADAMETER	TEST CONDITIONST	T .†	M	C79L050	C	МС	79L05A	۲C	
PARAMETER	TEST CONDITIONS	۰J+	MIN	TYP	MAX	MIN	TYP	MAX	UNIT
		25°C	-4.6	-5	-5.4	-4.8	-5	-5.2	
Output voltage§	$V_I = -7 V \text{ to } -20 V,$ $I_O = 1 \text{ mA to } 40 \text{ mA}$	Full range	-4.5		-5.5	-4.75		-5.25	V
	$V_I = -10 V$, $I_O = 1 mA$ to 70 mA	Full range	-4.5		-5.5	-4.75		-5.25	
	$V_{I} = -7 V \text{ to } -20 V$	25°C			200			150	mV
Input regulation	$V_{I} = -8 V \text{ to } -20 V$				150			100	
Ripple rejection	$V_{I} = -8 V \text{ to} - 18 V,$ f = 120 Hz	25°C	40	49		41	49		dB
	$I_{O} = 1 \text{ mA to } 100 \text{ mA}$	25°C			60			60	
Output regulation	$I_{O} = 1 \text{ mA to } 40 \text{ mA}$				30			30	mv
Output noise voltage	f = 10 Hz to 100 kHz	25°C		40			40		μV
Dropout voltage	I _O = 40 mA	25°C		1.7			1.7		V
Dies sument		25°C			6			6	
Blas current		125°C			5.5			5.5	mv
Rias ourront change	$V_{I} = -8 V \text{ to } -20 V$	Eull range			1.5			1.5	m\/
bias current change	$I_{O} = 1 \text{ mA to } 40 \text{ mA}$	Full range			0.2			0.1	mv

electrical characteristics at specified virtual junction temperature, $V_I = -19$ V, $I_O = 40$ mA (unless otherwise noted)

BADAMETED	TEST CONDITIONST	T .T	M	C79L12C	MC79L12AC			
PARAMETER	TEST CONDITIONS	1]+	MIN	TYP MAX	MIN	TYP	MAX	UNIT
		25°C	-11.1	-12 -12.9	-11.5	-12	-12.5	
Output voltage§	$V_{I} = -14.5 V \text{ to } -27 V,$ $I_{O} = 1 \text{ mA to } 40 \text{ mA}$	Full range	-10.8	-13.2	-11.4		-12.6	V
	$V_{I} = -19 V$, $I_{O} = 1 mA$ to 70 mA	Full range	-10.8	-13.2	-11.4		-12.6	
	$V_{I} = -14.5 \text{ V to } -27 \text{ V}$	25°C		250			250	mV
Input regulation	$V_I = -16 V \text{ to } -27 V$			200			200	
Ripple rejection	$V_{I} = -15 V \text{ to } -25 V,$ f = 120 Hz	25°C	36	42	37	42		dB
Output no sudation	$I_{O} = 1 \text{ mA to } 100 \text{ mA}$	0500		100			100	
Output regulation	$I_{O} = 1 \text{ mA to } 40 \text{ mA}$	25%		50			50	mv
Output noise voltage	f = 10 Hz to 100 kHz	25°C		80		80		μV
Dropout voltage	I _O = 40 mA	25°C		1.7		1.7		V
Diag current		25°C		6.5			6.5	
Blas current		125°C		6			6	mv
Bias current change	$V_{I} = -16 \text{ V to } -27 \text{ V}$	Full range		1.5			1.5	m\/
	$I_{O} = 1 \text{ mA to } 40 \text{ mA}$	Full range		0.2			0.1	- mv

[†] All characteristics are measured with a 0.33-μF capacitor across the input and a 0.1-μF capacitor across the output. Pulse-testing techniques are used to maintain the junction temperature as close to the ambient temperature as possible. Thermal effects must be taken into account separately.

[‡]Full range virtual junction temperature is 0°C to 125°C.

§ This specification applies only for dc power dissipation permitted by absolute maximum ratings.



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electrical characteristics at specified virtual junction temperature, $V_I = -23$ V, $I_O = 40$ mA (unless otherwise noted)

DADAMETER	TEST CONDITIONST	T . †	м	C79L15	C	MC				
	TEST CONDITIONST	1]+	MIN	TYP	MAX	MIN	TYP	MAX		
		25°C	-13.8	-15	-16.2	-14.4	-15	-15.6		
Output voltage§	$V_{I} = -17.5 V \text{ to } -30 V,$ $I_{O} = 1 \text{ mA to } 40 \text{ mA}$	Full range	-13.5		-16.5	-14.25		-15.75	V	
	$V_{I} = -23 V$, $I_{O} = 1 mA$ to 70 mA	Full range	-13.5		-16.5	-14.25		-15.75		
	$V_{I} = -17.5 \text{ V to } -30 \text{ V}$	25°C			300			300	mV	
Input regulation	$V_{I} = -17.5 \text{ V to } -30 \text{ V}$				250			250		
Ripple rejection	V _I = -18.5 V to -28.5 V, f = 120 Hz	25°C	33	39		34	39		dB	
Output regulation	$I_{O} = 1 \text{ mA to } 100 \text{ mA}$	0500	0500			150			150	
	$I_{O} = 1 \text{ mA to } 40 \text{ mA}$	25-0		75			75	IIIV		
Output noise voltage	f = 10 Hz to 100 kHz	25°C		90			90		μV	
Dropout voltage	I _O = 40 mA	25°C		1.7			1.7		V	
Pige current		25°C			6.5			6.5	m\/	
bias current		125°C			6			6	mv	
Bias current change	$V_{I} = -20 V \text{ to } -30 V$	Full range			1.5			1.5	m\/	
bias current change	$I_{O} = 1 \text{ mA to } 40 \text{ mA}$	i un range			0.2			0.1	1110	

[†] All characteristics are measured with a 0.33-μF capacitor across the input and a 0.1-μF capacitor across the output. Pulse-testing techniques are used to maintain the junction temperature as close to the ambient temperature as possible. Thermal effects must be taken into account separately.

[‡]Full range virtual junction temperature is 0°C to 125°C.

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